

Electronic Supplementary Information

Designed synthesis of Ag-functionalized Ni-doped In₂O₃ nanorods for high sensitive detection of formaldehyde gas

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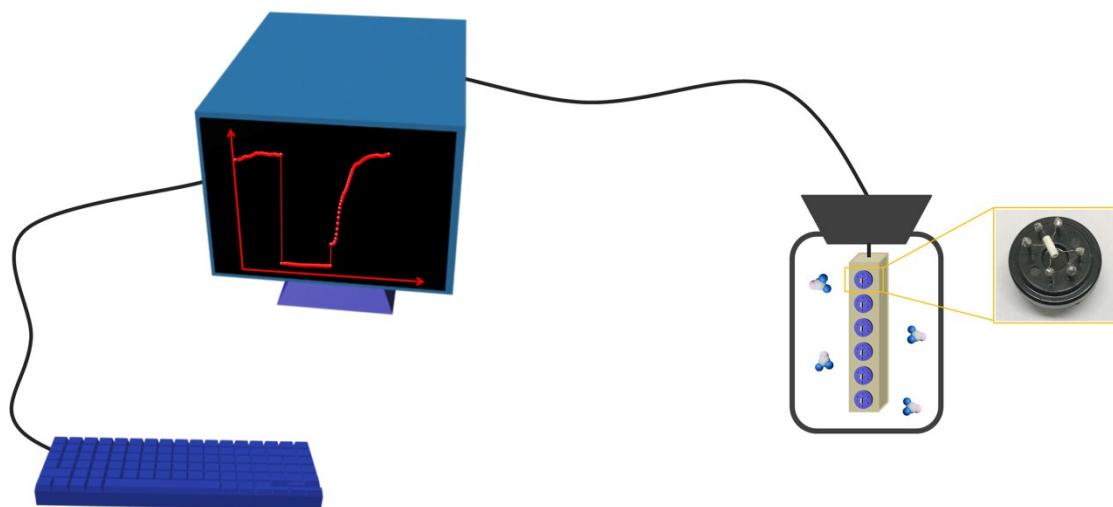


Fig. S1 The schematic illustration of formaldehyde testing assembly.

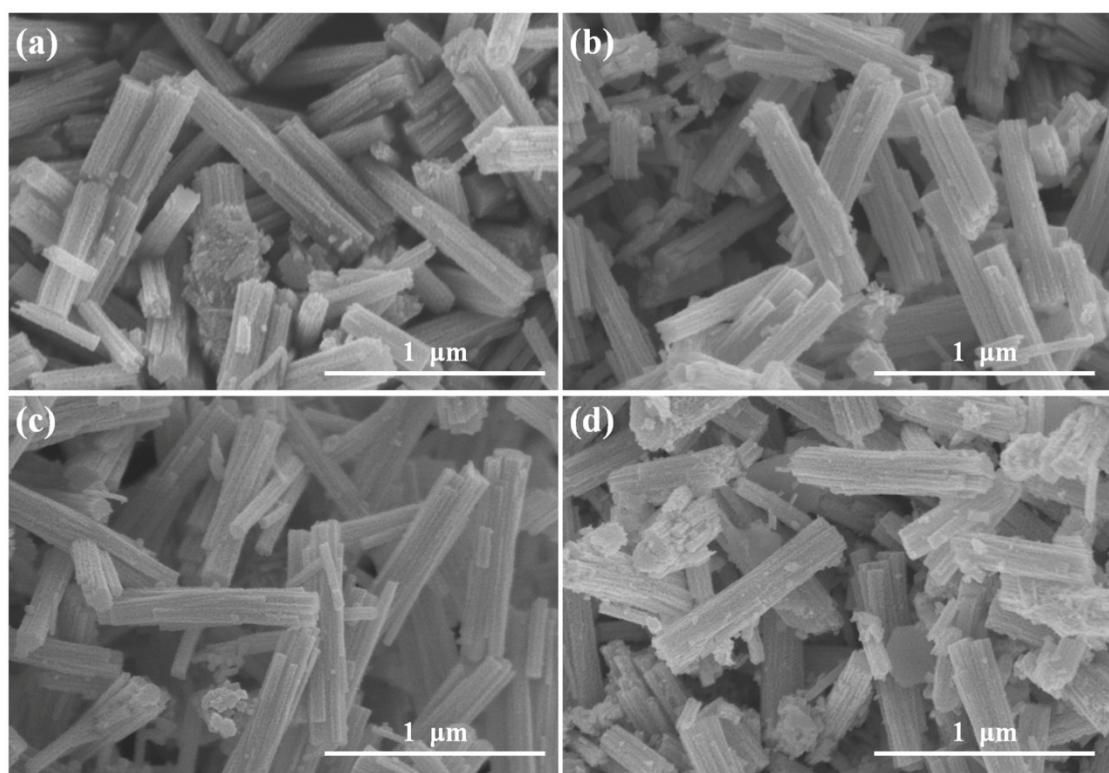


Fig. S2 SEM images of (a) $\text{Ni}_{2.5}\text{In}$, (b) $\text{Ni}_{7.5}\text{In}$, (c) 3%-Ag/ $\text{Ni}_{5.0}\text{In}$ and (d) 9%-Ag/ $\text{Ni}_{5.0}\text{In}$ samples.

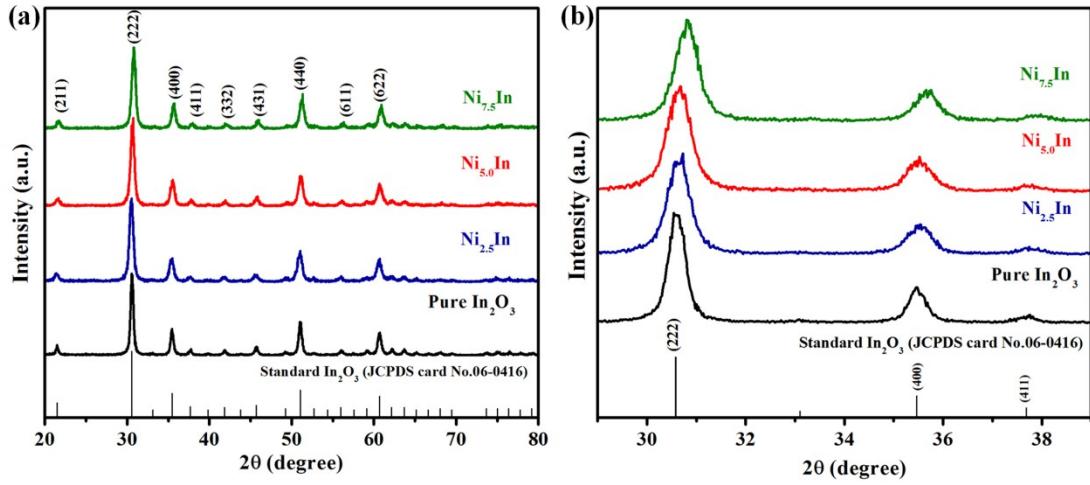


Fig. S3 (a) XRD patterns of pure In_2O_3 , $\text{Ni}_{2.5}\text{In}$, $\text{Ni}_{5.0}\text{In}$ and $\text{Ni}_{7.5}\text{In}$. (b) A partially enlarged view of the (222) and (400) segments of the XRD patterns.

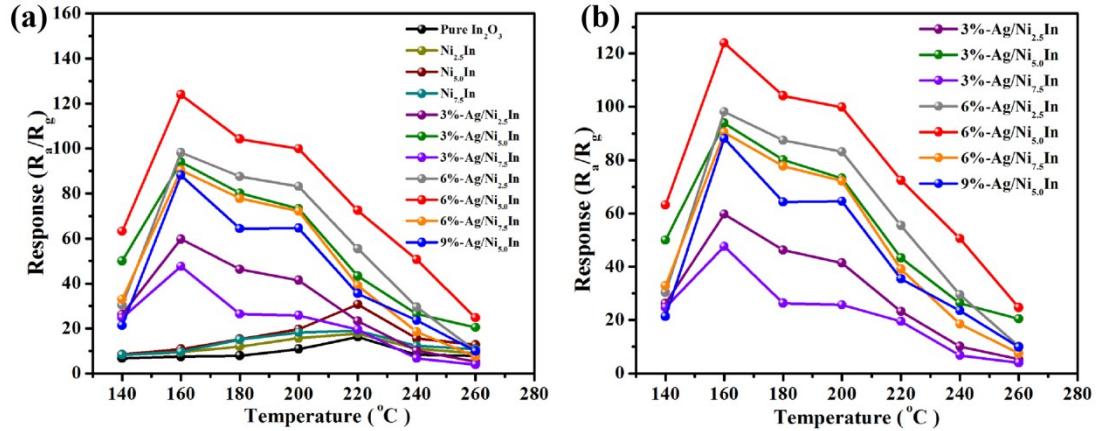


Fig. S4 (a) Response of the sensors to 100 ppm formaldehyde at the temperature range of 140-260 $^{\circ}\text{C}$ based on pure In_2O_3 , $\text{Ni}_{2.5}\text{In}$, $\text{Ni}_{5.0}\text{In}$, $\text{Ni}_{7.5}\text{In}$, 3%-Ag/ $\text{Ni}_{2.5}\text{In}$, 3%-Ag/ $\text{Ni}_{5.0}\text{In}$, 3%-Ag/ $\text{Ni}_{7.5}\text{In}$, 6%-Ag/ $\text{Ni}_{2.5}\text{In}$, 6%-Ag/ $\text{Ni}_{5.0}\text{In}$, 6%-Ag/ $\text{Ni}_{7.5}\text{In}$ and 9%-Ag/ $\text{Ni}_{5.0}\text{In}$ samples. (b) Response of the sensors to 100 ppm formaldehyde at the temperature range of 140-260 $^{\circ}\text{C}$ based on the obtained composites with different Ag loading rates.

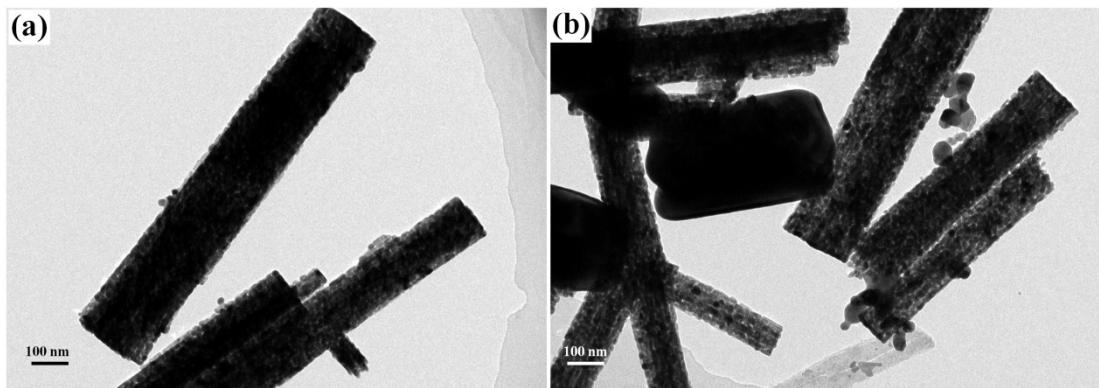


Fig. S5 (a) TEM image of CS1 after 1 h of chemical reduction. (b) TEM image of CS2 after 5 h of chemical reduction.

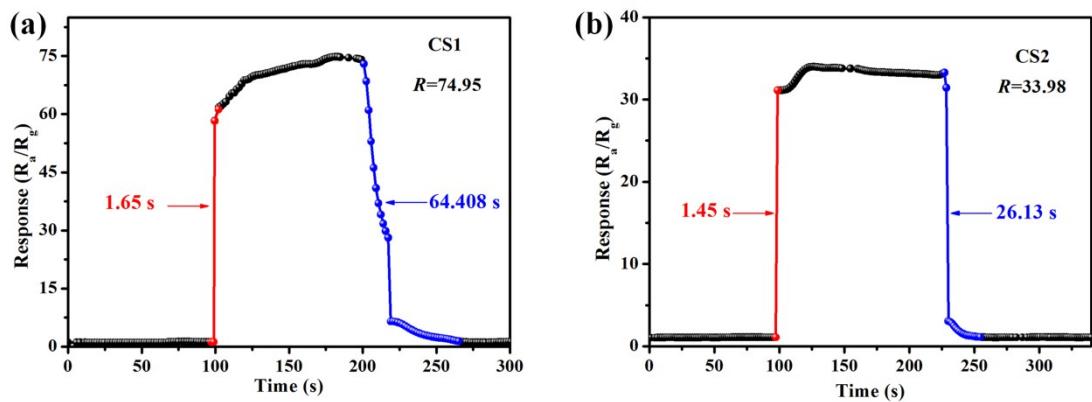


Fig. S6 (a-b) Response transients of sensors based on CS1 and CS2 samples toward 100 ppm formaldehyde at 160 °C.

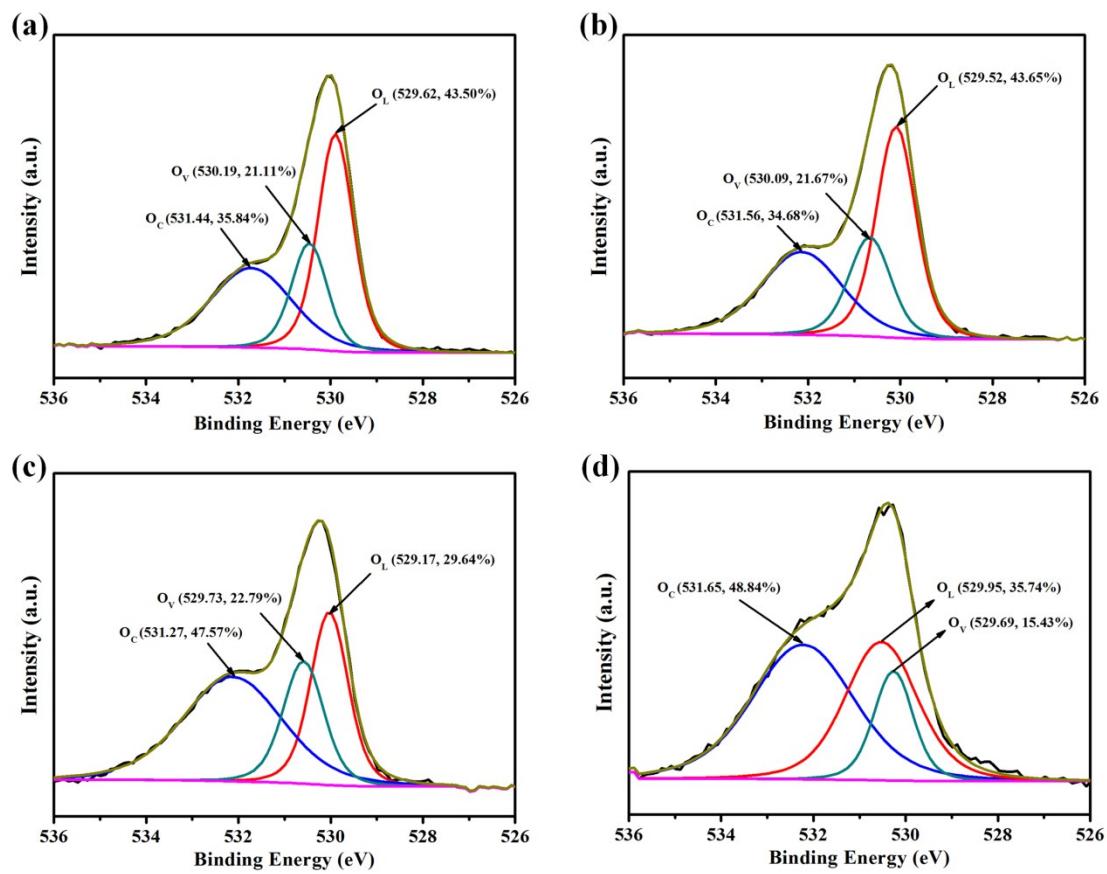


Fig. S7 O 1s XPS spectra of (a) $\text{Ni}_{2.5}\text{In}$, (b) $\text{Ni}_{7.5}\text{In}$, (c) 3%-Ag/ $\text{Ni}_{5.0}\text{In}$ and (d) 9%-Ag/ $\text{Ni}_{5.0}\text{In}$.

Table S1 Gas sensing properties of different sensing materials to formaldehyde, as reported in the literature and the present study.

sensing material	formaldehyde/con. (ppm)	temperature (°C)	response	res./rec. time (s)	referencce
rock-like ZnO	600	360	23.2	-	1
IrO ₂ -loaded Ga _{1.4} In _{0.6} O ₃ nanofibers	10	280	46	2/9	2
Ag/Ag ₂ O functioned SnO ₂ /Sn ₃ O ₄	100	160	12.76	5/5	3
Ce-Sn ₃ O ₄ microsphere	100	200	5.5	4/8	4
Tb-doped In ₂ O ₃ nanotubes	50	160	75	2/12	5
SnO ₂ microspheres	100	200	38.3	17/25	6
Er-doped In ₂ O ₃ nanotubes	20	260	12	5/38	7
NiO/SnO ₂ microflowers	100	100	39.2	28/115	8
SnO ₂ hollow microspheres	50	300	6.4	-	9
Nd-doped In ₂ O ₃	100	240	44.6	15/50	10
Porous NiO/SnO ₂ microspheres	100	200	27.6	6/17	11
Li-doped ZnO nanoparticle	100	350	40.2	8/26	12
Ag functionalized Ni-doped In ₂ O ₃ nanorods	100	160	123.97	1.45/58.2	This work

References

1. L. Zhu, W. Zeng, H. Ye, Y. Li, *Mater. Res. Bull.*, 2018, **100**, 259–264.
2. Q. Gao, S. Ao, H. Chen, X. Zou, C. Wei, G. Li, *J. Alloy. Compd.*, 2018, **732**, 856-862.
3. H. Yu, J. Li, Y. Tian, Z. Li, *J. Alloy. Compd.*, 2018, **765**, 624-634.
4. X. Ma, J. Shen, D. Hu, L. Sun, Y. Chen, M. Liu, C. Li, S. Ruan, *J. Alloy. Compd.*, 2017, **726**, 1092-1100.
5. H. Duan, Y. He, S. Li, L. Liu, S. Xu, Y. Li, H. Li, Y. Gong, Q. Liang, Y. Cheng, *J. Mater. Sci.-Mater. Electron.*, 2018, **29**, 19111-19122.
6. Y. Li, N. Chen, D. Deng, X. Xing, X. Xiao, Y. Wang, *Sens. Actuators B*, 2017, **238**, 264-273.
7. X. Wang, J. Zhang, L. Wang, S. Li, L. Liu, C. Su, L. Liu, *J. Mater. Sci. Technol.*, 2015, **31**, 1175-1180.
8. D. Meng, D. Liu, G. Wang, Y. Shen, X. San, M. Li, F. Meng, *Sens. Actuators B*, 2018, **273**, 418-428.
9. J. Yang, S. Wang, R. Dong, L. Zhang, Z. Zhu, X. Gao, *Mater. Lett.*, 2016, **184**, 9-12.
10. X. Wang, J. Zhang, Y. He, L. Wang, L. Liu, H. Wang, X. Guo, H. Lian, *Chem. Phys. Lett.*, 2016, **658**, 319-323.
11. C. Gu, Y. Cui, L. Wang, E. Sheng, J. Shim, J. Huang, *Sens. Actuators B*, 2017, **241**, 298-307.
12. J. Zhao, C. Xie, L. Yang, S. Zhang, G. Zhang, Z. Cai, *Appl. Surf. Sci.*, 2015, **330**, 126-133.